

Applications

- Industrial UPS
- Welding machine
- Solar converters
- Energy Storage
- Mid to high range switching frequency converters

Features

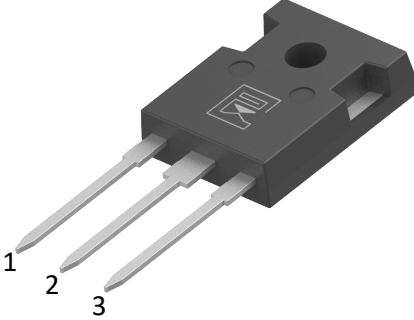
- Low $V_{CE(sat)}$
- High speed switching
- High ruggedness, temperature stable
- Positive temperature coefficient in $V_{CE(sat)}$
- Enhanced avalanche capability

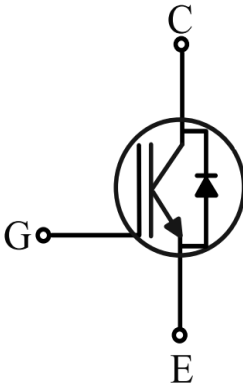
Product Summary

| | | |
|------------------------|-----|---|
| V_{CES} | 650 | V |
| I_C | 60 | A |
| $V_{CE(sat), Typ@15V}$ | 1.8 | V |



TO-247L





Gate: 1
Collector: 2
Emitter: 3

Package Marking and Ordering Information

| Ordering code | Marking | Package | Packaging | Min. package quantity |
|---------------|---------------|---------|-----------|-----------------------|
| MSLB60N065J2F | MSLB60N065J2F | TO-247L | Tube | 450 |

»» Absolute Maximum Ratings (Tc=25°C unless otherwise noted)

| Parameter | Symbol | Ratings | Unit |
|---|----------------|----------|------|
| Collector-emitter Voltage | V_{CES} | 650 | V |
| DC collector current, limited by T_{jmax} TC=25°C TC=100°C | I_C | 90 60 | A |
| Pulsed collector current, tp limited by T_{jmax} | $I_{C\ Pulse}$ | 180 | A |
| Diode forward current, limited by T_{jmax} TC=25°C TC=100°C | I_F | 90 60 | A |
| Diode Pulsed current, tp limited by T_{jmax} | $I_{F\ Pulse}$ | 180 | A |
| Continuous Gate-emitter voltage | V_{GE} | ±20 | V |
| Power Dissipation (TC=25°C) | P_D | 312 | W |
| Junction Temperature | T_J | 175 | °C |
| Storage Temperature | T_{STG} | -55-150 | °C |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

»» Thermal Characteristics

| Parameter | Symbol | Max | Unit |
|--------------------------------|-----------------|------|------|
| IGBT Maximum Junction-to-Case | $R_{\theta JC}$ | 0.48 | °C/W |
| Diode Maximum Junction-to-Case | $R_{\theta JC}$ | 0.45 | °C/W |
| Maximum Junction-to-Ambient | $R_{\theta JA}$ | 40 | °C/W |

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

Electrical Characteristics (Tc=25°C unless otherwise noted)

| Parameter | Symbol | Test Condition | Min | Typ | Max | Unit |
|--|---------------|------------------------------------|-----|------|-----------|----------|
| Static Characteristics | | | | | | |
| Collector-emitter Breakdown Voltage | BV_{CES} | $V_{GE}=0V, I_C=250\mu A$ | 650 | - | - | V |
| Zero gate voltage collector current | I_{CES} | $V_{CE}=650V, V_{GE}=0V$ | - | - | 20 | μA |
| Gate-emitter leakage current | I_{GES} | $V_{GE}=\pm 20V, V_{CE}=0V$ | - | - | ± 200 | nA |
| Gate-emitter threshold voltage | $V_{GE(TH)}$ | $V_{CE}=V_{GE}, I_C=250\mu A$ | 3.5 | 4.6 | 5.5 | V |
| Collector-emitter saturation voltage | $V_{CE(sat)}$ | $V_{GE}=15V, I_C=60A$ | - | 1.8 | 2.3 | V |
| | | $T_j=150^\circ C$ | - | 2.3 | - | V |
| Diode forward voltage | V_F | $I_F=60A$ | - | 2.1 | 2.5 | V |
| | | $T_j=150^\circ C$ | - | 1.7 | - | V |
| Dynamic Characteristics | | | | | | |
| Input Capacitance | C_{ies} | $V_{CE}=25V, V_{GE}=0V, f=1.0MHz$ | - | 2740 | - | pF |
| Output Capacitance | C_{oes} | | - | 236 | - | pF |
| Reverse Transfer Capacitance | C_{res} | | - | 66 | - | pF |
| Integrated gate resistor | R_{Gint} | | - | 3.5 | - | Ω |
| Total Gate Charge | Q_g | $V_{CE}=400V, I_C=60A, V_{GE}=15V$ | - | 99 | - | nC |
| Gate-to-emitter charge | Q_{ge} | | - | 12 | - | nC |
| Gate-to-collector charge | Q_{gc} | | - | 36 | - | nC |
| Internal emitter inductance measured 5mm (0.197 in.) from case | L_E | | - | 13 | - | nH |

Switching Characteristic, Inductive Load, at $T_j=25^\circ\text{C}$

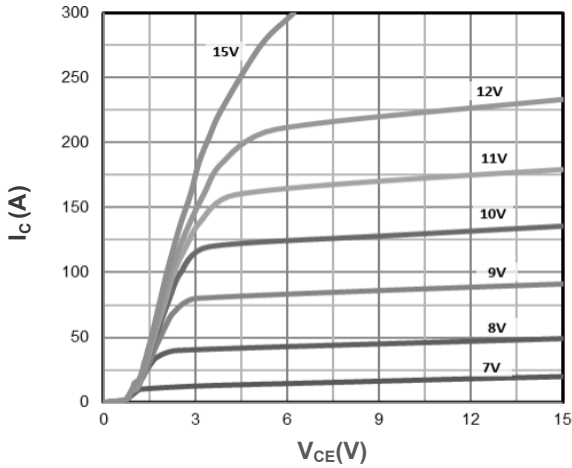
| Parameter | Symbol | Test Condition | Min | Typ | Max | Unit |
|---------------------------------------|--------------|---|-----|------|-----|---------------|
| IGBT Switching Characteristics | | | | | | |
| Turn-On Delay Time | $t_{d(on)}$ | $V_{CC}= 400V$ $I_C= 60A$ $V_{GE}= 15V$ $R_G= 8.2\Omega$ Inductive load | - | 23 | - | ns |
| Turn-On Rise Time | t_r | | - | 31 | - | ns |
| Turn-Off Delay Time | $t_{d(off)}$ | | - | 120 | - | ns |
| Turn-Off Fall Time | t_f | | - | 39 | - | ns |
| Turn-on energy | E_{on} | | - | 1.11 | - | mJ |
| Turn-off energy | E_{off} | | - | 0.61 | - | mJ |
| Diode Characteristics | | | | | | |
| Reverse Recovery Time | t_{rr} | $V_R=400, I_F=30A,$ $di/dt=200A/us$ | - | 60 | - | ns |
| Reverse Recovery Charge | Q_{rr} | | - | 0.26 | - | μC |
| Peak Reverse Recovery Current | I_{rrm} | | - | 8.6 | - | A |

Switching Characteristic, Inductive Load, at $T_j=150^\circ\text{C}$

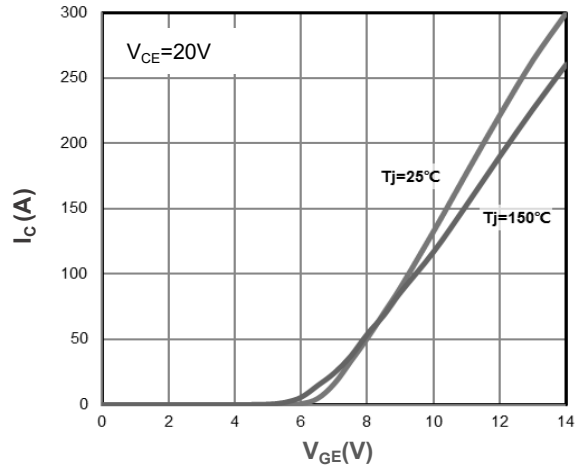
| Parameter | Symbol | Test Condition | Min | Typ | Max | Unit |
|---------------------------------------|--------------|---|-----|------|-----|---------------|
| IGBT Switching Characteristics | | | | | | |
| Turn-On Delay Time | $t_{d(on)}$ | $V_{CC}= 400V$ $I_C= 60A$ $V_{GE}= 15V$ $R_G= 8.2\Omega$ Inductive load | - | 23 | - | ns |
| Turn-On Rise Time | t_r | | - | 35 | - | ns |
| Turn-Off Delay Time | $t_{d(off)}$ | | - | 132 | - | ns |
| Turn-Off Fall Time | t_f | | - | 37 | - | ns |
| Turn-on energy | E_{on} | | - | 1.52 | - | mJ |
| Turn-off energy | E_{off} | | - | 0.74 | - | mJ |
| Diode Characteristics | | | | | | |
| Reverse Recovery Time | t_{rr} | $V_R=400, I_F=30A,$ $di/dt=200A/us$ | - | 110 | - | ns |
| Reverse Recovery Charge | Q_{rr} | | - | 0.72 | - | μC |
| Peak Reverse Recovery Current | I_{rrm} | | - | 13 | - | A |



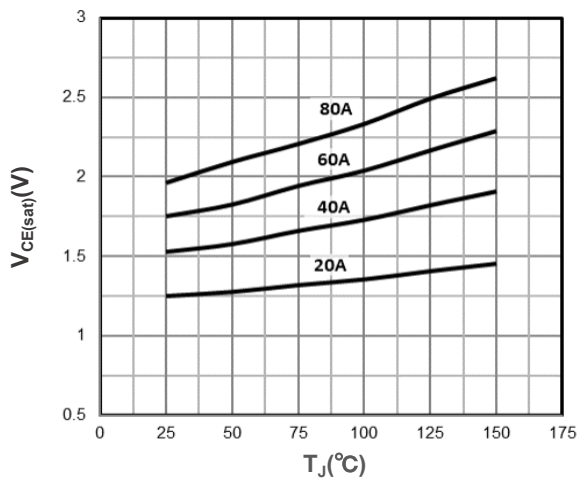
» Characteristics Curves



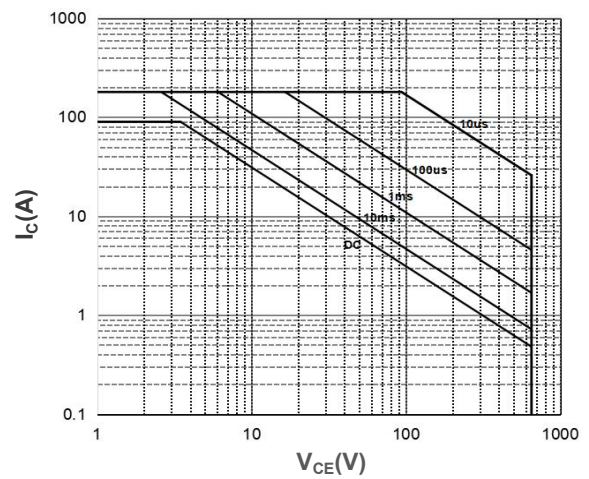
Output Characteristics



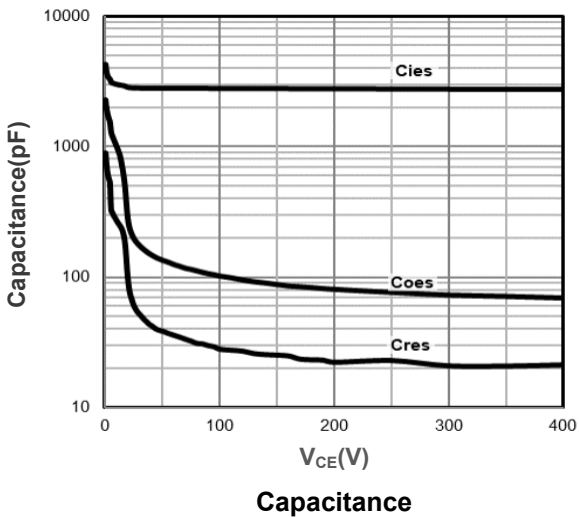
Transfer Characteristics



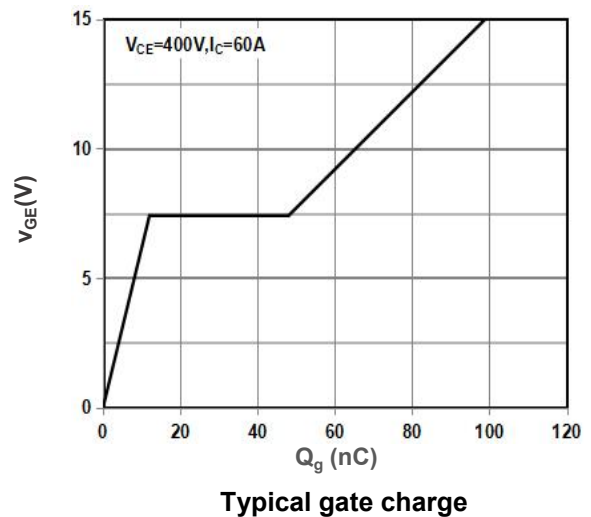
"Typical collector-emitter saturation voltage as a function of junction temperature " ($V_{GE} = 15V$)



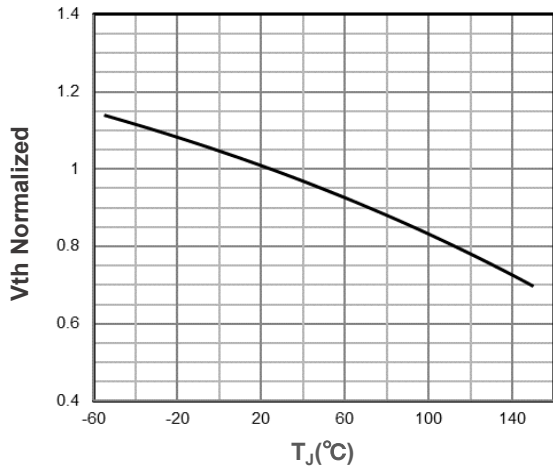
Maximum Safe Operating Area ($T_a = 25^\circ C$)



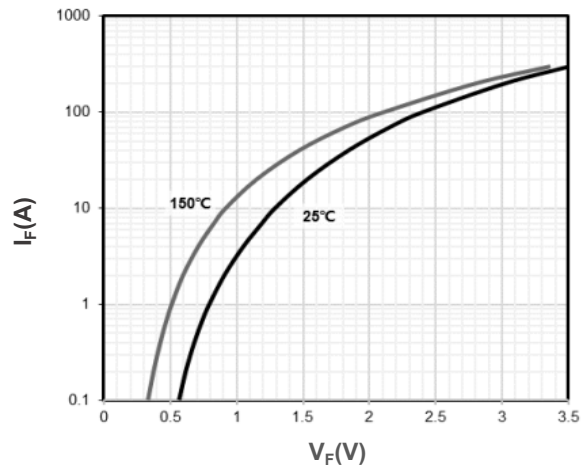
Capacitance



Typical gate charge



Gate-emitter threshold voltage as a function of junction temperature



Typ. diode forward current as a function of forward voltage

Note : The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



TO-247L Package Dimensions

Unit: mm

| Symbol | Min | Nom | Max | Symbol | Min | Nom | Max |
|--------|-------|-------|-------|--------|-------|------|-------|
| A1 | 2.20 | 2.40 | 2.60 | E2 | 5.00 | | 5.50 |
| A2 | 1.85 | | 2.15 | E3 | 1.90 | | 2.60 |
| b | 1.07 | | 1.33 | e | | 5.44 | |
| b2 | 1.90 | | 2.16 | L | 19.30 | | 19.90 |
| b4 | 2.90 | | 3.20 | L1 | 3.95 | 4.15 | 4.35 |
| c | 0.52 | | 0.68 | ΦP | 3.40 | | 3.80 |
| D | 20.70 | 20.80 | 21.30 | ΦP1 | 7.00 | | 7.40 |
| D1 | 16.15 | | 16.95 | S | 6.04 | 6.15 | 6.30 |
| E | 15.50 | 15.60 | 16.10 | | | | |

